

SN65LBC170, SN75LBC170 TRIPLE DIFFERENTIAL TRANSCEIVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

- Three Differential Transceivers in One Package
- Signaling Rates[†] Up to 30 Mbps
- Low Power and High Speed
- Designed for TIA/EIA-485, TIA/EIA-422, ISO 8482, and ANSI X3.277 (HVD SCSI Fast-20) Applications
- Common-Mode Bus Voltage Range –7 V to 12 V
- ESD Protection on Bus Terminals Exceeds 12 kV
- Driver Output Current up to ± 60 mA
- Thermal Shutdown Protection
- Driver Positive and Negative Current Limiting
- Power-Up, Power-Down Glitch-Free Operation
- Pin-Compatible With the SN75ALS170
- Available in Shrink Small-Outline Package

description

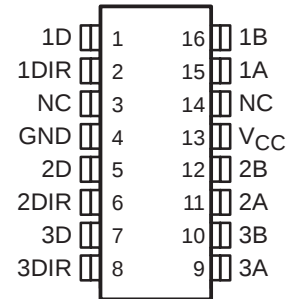
The SN65LBC170 and SN75LBC170 are monolithic integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. Potential applications include serial or parallel data transmission, cabled peripheral buses with twin axial, ribbon, or twisted-pair cabling. These devices are suitable for FAST-20 SCSI and can transmit or receive data pulses as short as 25 ns, with skew less than 3 ns.

These devices combine three 3-state differential line drivers and three differential input line receivers, all of which operate from a single 5-V power supply.

The driver differential outputs and the receiver differential inputs are connected internally to form three differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. These ports feature a wide common-mode voltage range making the device suitable for party-line applications over long cable runs.

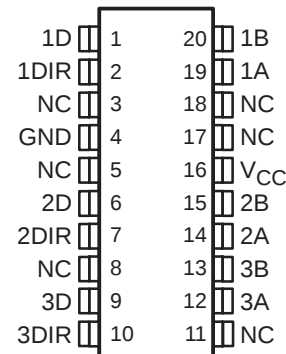
SN65LBC170DB (marked as BL170)
SN75LBC170DB (marked as BL170)

(TOP VIEW)



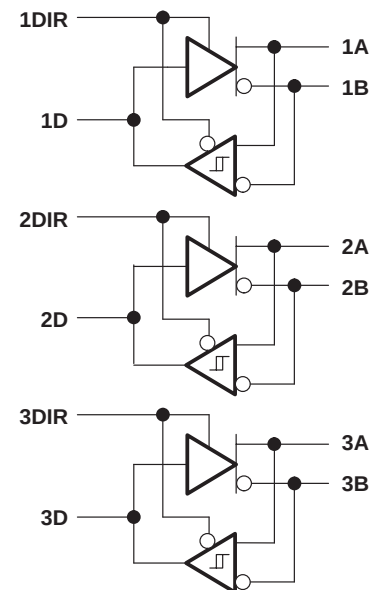
SN65LBC170DW (marked as 65LBC170)
SN75LBC170DW (marked as 75LBC170)

(TOP VIEW)



NC – No internal connection

logic diagram



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

[†]The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2002, Texas Instruments Incorporated

SN65LBC170, SN75LBC170

TRIPLE DIFFERENTIAL TRANSCEIVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

description (continued)

The driver's active-high enable and the receiver's active-low enable are tied together internally and provide a direction input for each driver/receiver pair.

The SN75LBC170 is characterized for operation over the temperature range of 0°C to 70°C. The SN65LBC170 is characterized for operation over the temperature range of -40°C to 85°C.

AVAILABLE OPTIONS†

T _A	PACKAGE	
	PLASTIC SHRINK SMALL-OUTLINE (JEDEC MO-150)	PLASTIC SMALL-OUTLINE (JEDEC MS-013)
0°C to 70°C	SN75LBC170DB	SN75LBC170DW
-40°C to 85°C	SN65LBC170DB	SN65LBC170DW

† Add R suffix for taped and reel

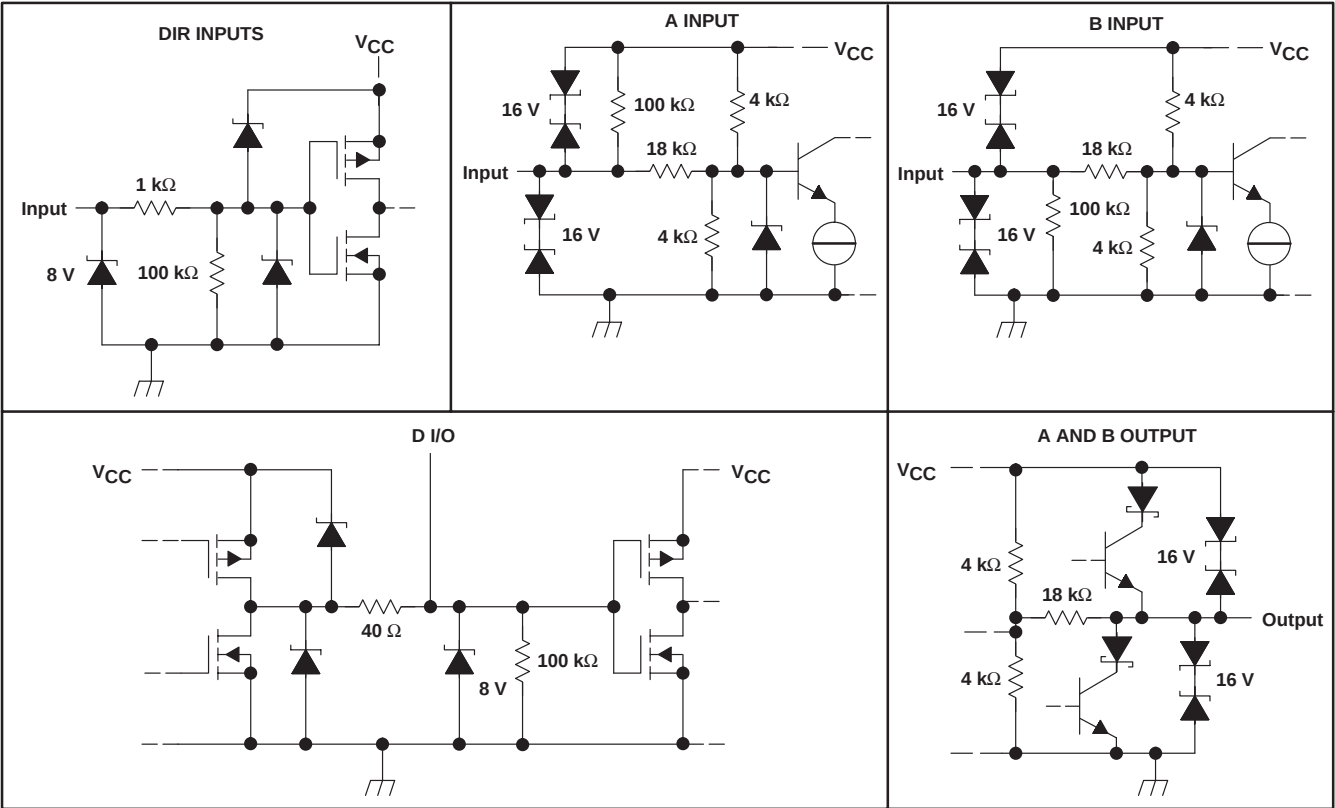
† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

Function Tables

EACH DRIVER			EACH RECEIVER		
INPUT D	ENABLE DIR	OUTPUTS	DIFFERENTIAL INPUT (V _A -V _B)	ENABLE DIR	OUTPUT D
		A B			
H	H	H L	V _{ID} ≥ 0.2 V	L	H
L	H	L H	-0.2 V < V _{ID} < 0.2 V	L	?
OPEN	H	L H	V _{ID} ≤ -0.2 V	L	L
X	L	Z Z	X	H	Z
X	OPEN	X X	OPEN	L	H

H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

equivalent input and output schematic diagrams



SN65LBC170, SN75LBC170 TRIPLE DIFFERENTIAL TRANSCEIVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

absolute maximum ratings[†] over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1)	–0.3 V to 6 V
Voltage range at any bus I/O terminal (steady state)	–10 V to 15 V
Voltage input range, A and B, (transient pulse through 100 Ω , see Figure 12)	–30 V to 30 V
Voltage range at any D or DIR terminal	–0.5 V to $V_{CC} + 0.5$ V
Receiver output current, I_O	± 10 mA
Electrostatic discharge: Human body model (A, B, GND) (see Note 2)	12 kV
All pins	5 kV
Charged-device model (all pins) (see Note 3)	1 kV
Continuous total power dissipation	See Power Dissipation Rating Table

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
2. Tested in accordance with JEDEC Standard 22, Test Method A114–A.
3. Tested in accordance with JEDEC Standard 22, Test Method C101.

POWER DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR [‡] ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DB	995 mW	8.0 mW/ $^\circ\text{C}$	635 mW	515 mW
DW	1480 mW	11.8 mW/ $^\circ\text{C}$	950 mW	770 mW

[‡] This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus I/O terminal	A, B	−7		12	V
High-level input voltage, V _{IH}	D, DIR	2	V _{CC}		V
Low-level input voltage, V _{IL}		0	0.8		
Differential input voltage, V _{ID}	A with respect to B	−12		12	V
Output current	Driver	−60		60	mA
	Receiver	−8		8	
Operating free-air temperature, T _A	SN75LBC170	0		70	°C
	SN65LBC170	−40		85	



SN65LBC170, SN75LBC170

TRIPLE DIFFERENTIAL TRANSCEIVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

DRIVER SECTION

electrical characteristics over recommended operating conditions

PARAMETER			TEST CONDITIONS		MIN	TYP [†]	MAX	UNIT
V _{IK}	Input clamp voltage	D and DIR	I _I = 18 mA		-1.5	-0.7		V
V _O	Open-circuit output voltage (single-ended)		A or B, No load		0		V _{CC}	V
V _{OD(SS)}	Steady-state differential output voltage magnitude [‡]		No load		3.8	4.3	V _{CC}	V
			R _L = 54 Ω, See Figure 1		1	1.6	2.4	
			With common-mode loading, See Figure 2		1	1.6	2.4	
ΔV _{OD}	Change in differential output voltage magnitude, V _{OD(H)} – V _{OD(L)}		R _L = 54 Ω, C _L = 50 pF	See Figure 1	-0.2		0.2	V
V _{OC(SS)}	Steady-state common-mode output voltage				2		2.4	
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage (V _{OC(H)} – V _{OC(L)})						-0.2	
I _I	Input current		D, DIR		-100		100	μA
I _O	Output current with power off		V _{CC} = 0 V, V _O = -7 V to 12 V		-700		900	μA
I _{OS}	Short-circuit output current		V _O = -7 V to 12 V, See Figure 7		-250		250	mA
I _{CC}	Supply current (driver enabled)		D at 0 V or V _{CC} , DIR at V _{CC} , No load		14		20	mA

[†] All typical values are at V_{CC} = 5 V and T_A = 25°C.

[‡] The minimum V_{OD} may not fully comply with TIA/EIA-485-A at operating temperatures below 0°C. System designers should take the possibly lower output signal into account in determining the maximum signal-transmission distance.

switching characteristics over recommended operating conditions

PARAMETER			TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _{PLH}	Differential output propagation delay, low-to-high		R _L = 54 Ω, C _L = 50 pF, See Figure 3		4	8.5	12	ns
t _{PHL}	Differential output propagation delay, high-to-low				4	8.5	11	
t _r	Differential output rise time				3	7.5	11	
t _f	Differential output fall time				3	7.5	11	
t _{sk(p)}	Pulse skew (t _{PLH} – t _{PHL})						2	
t _{sk(o)}	Output skew [§]						1.5	
t _{sk(pp)}	Part-to-part skew [¶]						2	
t _{PLH}	Differential output propagation delay, low-to-high		See Figure 4, (HVD SCSI double-terminated load)		3	7	10	ns
t _{PHL}	Differential output propagation delay, high-to-low				3	7.5	10	
t _r	Differential output rise time				3	7.5	12	
t _f	Differential output fall time				3	7.5	12	
t _{sk(p)}	Pulse skew (t _{PLH} – t _{PHL})						3	
t _{sk(o)}	Output skew [§]						1.5	
t _{sk(pp)}	Part-to-part skew [¶]						2.5	
t _{pZH}	Output enable time to high level		See Figure 5			15	25	ns
t _{pHZ}	Output disable time from high level					18	25	
t _{pZL}	Output enable time to low level		See Figure 6			10	25	ns
t _{pLZ}	Output disable time from low level					17	25	

[§] Output skew (t_{sk(o)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together.

[¶] Part-to-part skew (t_{sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.

RECEIVER SECTION

electrical characteristics over recommended operating conditions

PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V _{IT+} Positive-going differential input voltage threshold	See Figure 8			0.2	V
V _{IT-} Negative-going differential input voltage threshold		-0.2			
V _{hys} Hysteresis voltage (V _{IT+} - V _{IT-})			40		mV
V _{OH} High-level output voltage	V _{ID} = 200 mV, I _{OH} = -8 mA, See Figure 8	4	4.7	V _{CC}	V
V _{OL} Low-level output voltage	V _{ID} = -200 mV, I _{OL} = -8 mA, See Figure 8	0	0.2	0.4	
I _I Line input current	Other input = 0 V	V _I = 12 V		0.9	mA
		V _I = -7 V		-0.7	
R _I Input resistance	A, B	12			kΩ
I _{CC} Supply current (receiver enabled)	A, B, D, and DIR open			16	mA

[†] All typical values are at V_{CC} = 5 V and T_A = 25°C.

switching characteristics over recommended operating conditions

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH} Propagation delay time, low-to-high level output	See Figure 9	7		16	ns
t _{PHL} Propagation delay time, high-to-low level output		7		16	ns
t _r Receiver output rise time			1.3	3	ns
t _f Receiver output fall time			1.3	3	ns
t _{PZH} Receiver output enable time to high level	See Figure 10		26	40	ns
t _{PHZ} Receiver output disable time from high level				40	
t _{PZL} Receiver output enable time to low level	See Figure 11		29	40	ns
t _{PLZ} Receiver output enable time to high level				40	
t _{sk(p)} Pulse skew (t _{PLH} - t _{PHL})				2	ns
t _{sk(o)} Output skew [‡]				1.5	ns
t _{sk(pp)} Part-to-part skew [§]				3	ns

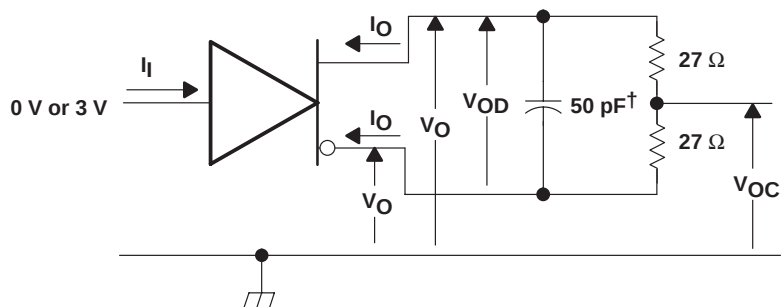
[‡] Output skew (t_{sk(o)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together.

[§] Part-to-part skew (t_{sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.

SN65LBC170, SN75LBC170 TRIPLE DIFFERENTIAL TRANSCIEVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

PARAMETER MEASUREMENT INFORMATION



† Includes probe and jig capacitance

Figure 1. Driver Test Circuit, V_{OD} and V_{OC} Without Common-Mode Loading

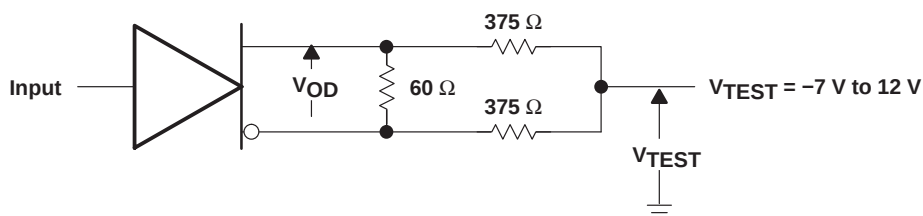
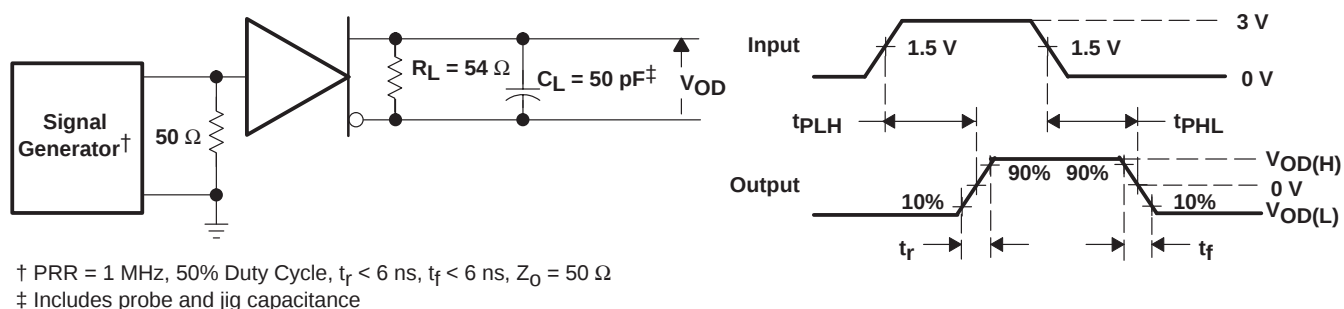


Figure 2. Driver Test Circuit, V_{OD} With Common-Mode Loading

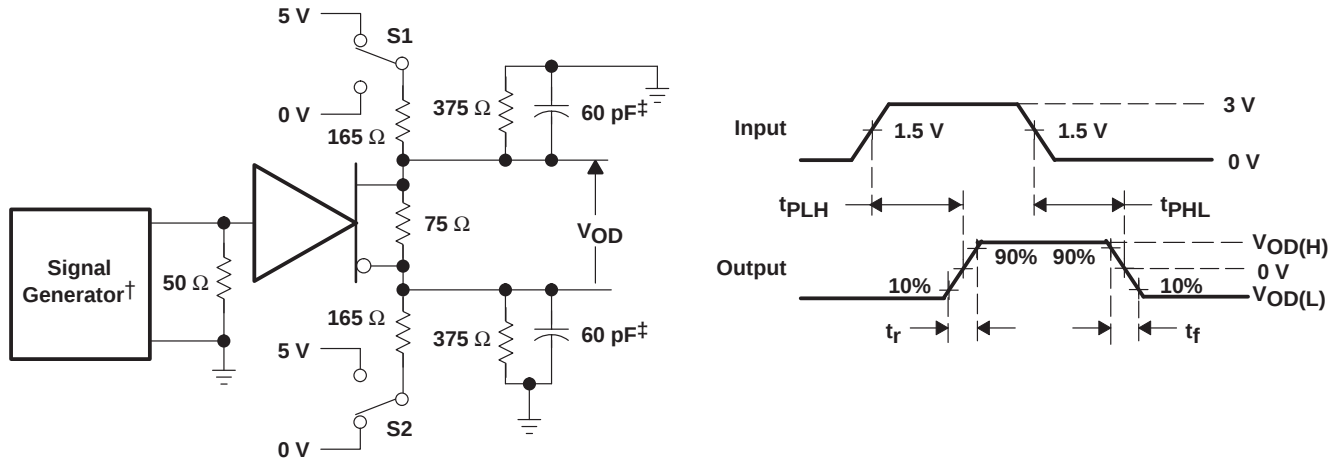


† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_0 = 50 \Omega$

‡ Includes probe and jig capacitance

Figure 3. Driver Switching Test Circuit and Waveforms, 485-Loading

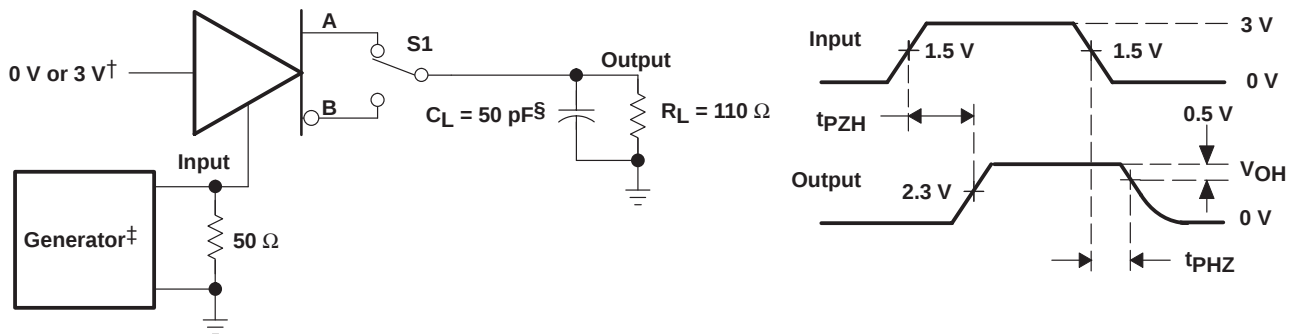
PARAMETER MEASUREMENT INFORMATION



† PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z₀ = 50 Ω

‡ Includes probe and jig capacitance

Figure 4. Driver Switching Test Circuit and Waveforms, HVD SCSI-Loading (double terminated)

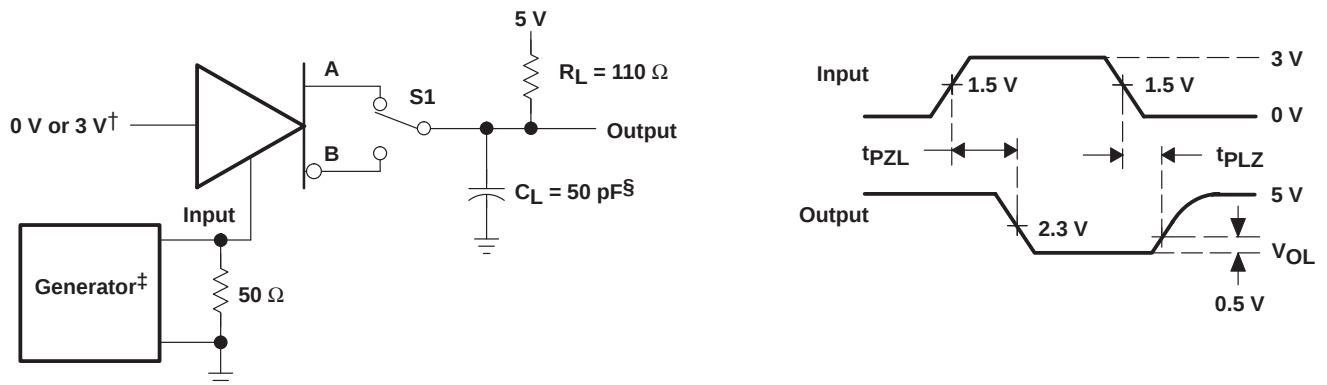


† 3 V if testing A output, 0 V if testing B output

‡ PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z₀ = 50 Ω

§ Includes probe and jig capacitance

Figure 5. Driver Enable/Disable Test, High Output



† 0 V if testing A output, 3 V if testing B output

‡ PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z₀ = 50 Ω

§ Includes probe and jig capacitance

Figure 6. Driver Enable/Disable Test, Low Output

SN65LBC170, SN75LBC170 TRIPLE DIFFERENTIAL TRANSCIEVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

PARAMETER MEASUREMENT INFORMATION

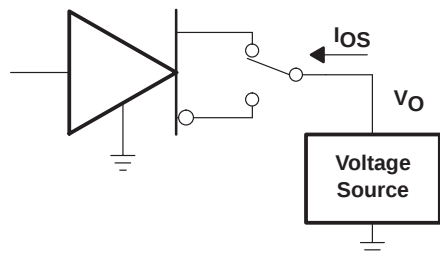


Figure 7. Driver Short-Circuit Test

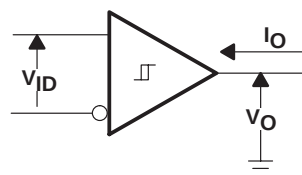
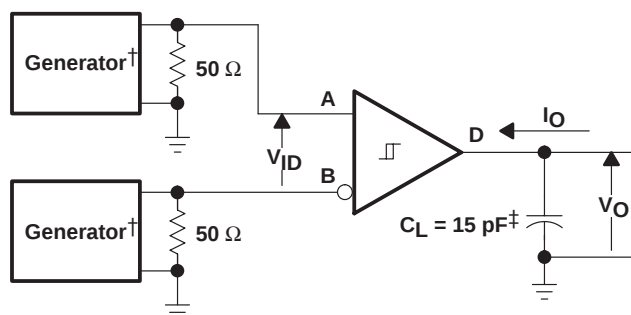
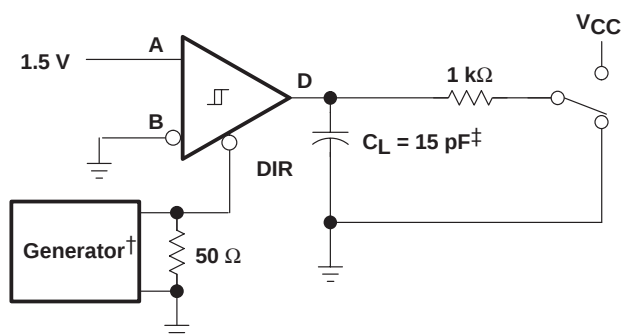


Figure 8. Receiver DC Parameters



† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_0 = 50 \Omega$
‡ Includes probe and jig capacitance

Figure 9. Receiver Switching Test Circuit and Waveforms



† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_0 = 50 \Omega$
‡ Includes probe and jig capacitance

Figure 10. Receiver Enable/Disable Test, High Output

PARAMETER MEASUREMENT INFORMATION

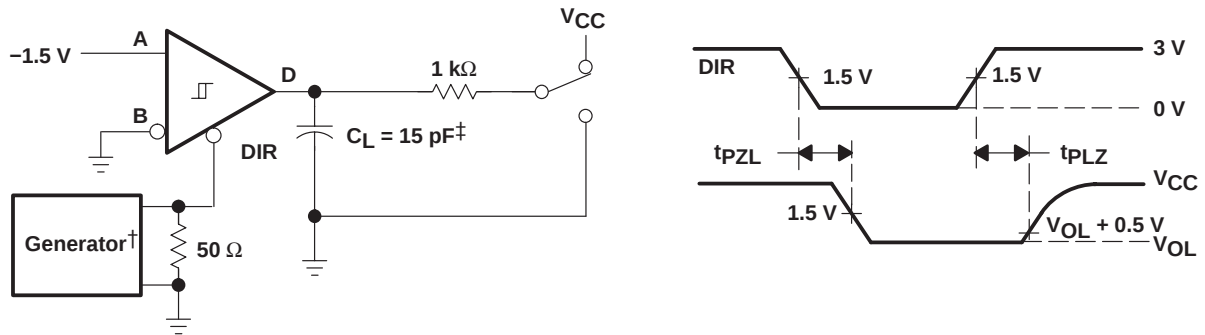


Figure 11. Receiver Enable/Disable Test, Low Output

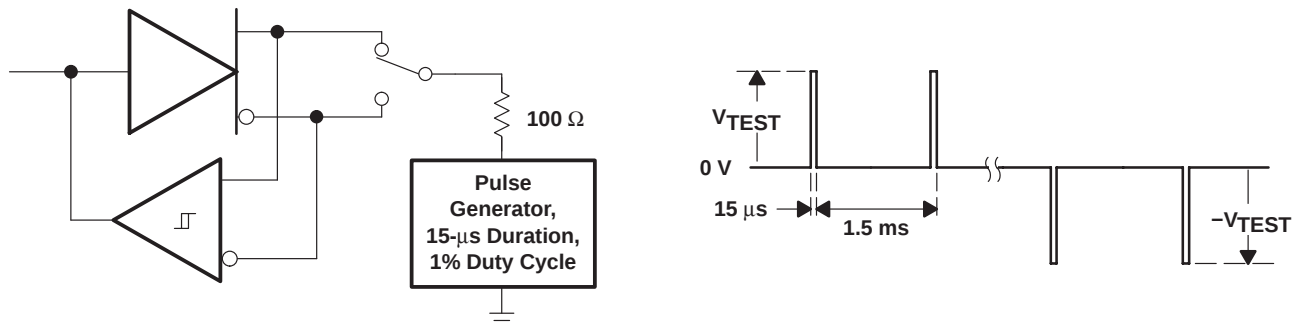


Figure 12. Test Circuit and Waveform, Transient Over Voltage Test

SN65LBC170, SN75LBC170 TRIPLE DIFFERENTIAL TRANSCEIVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

TYPICAL CHARACTERISTICS

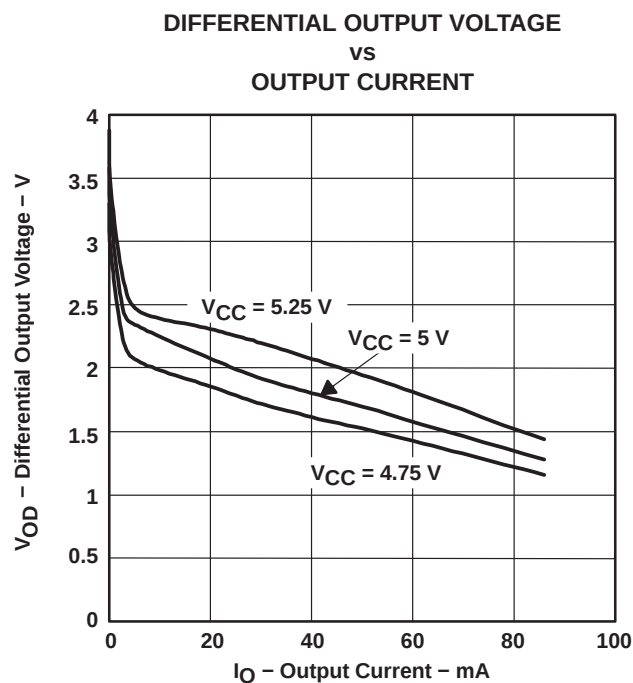


Figure 13

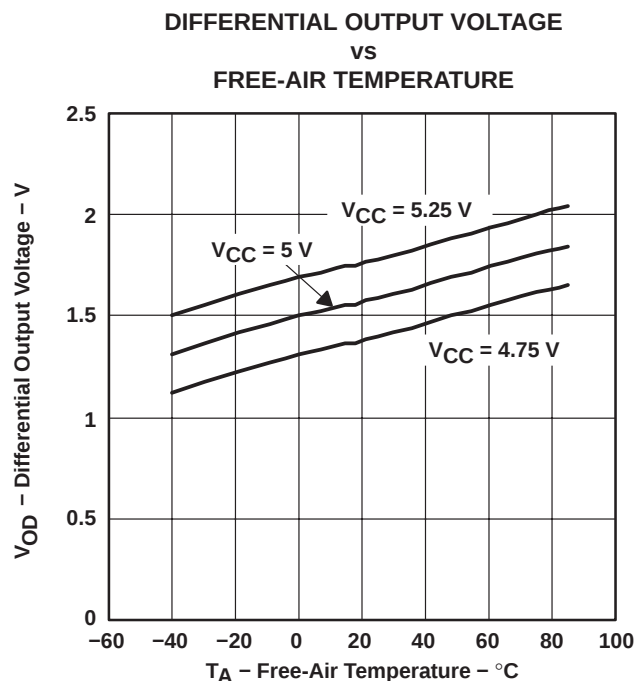


Figure 14

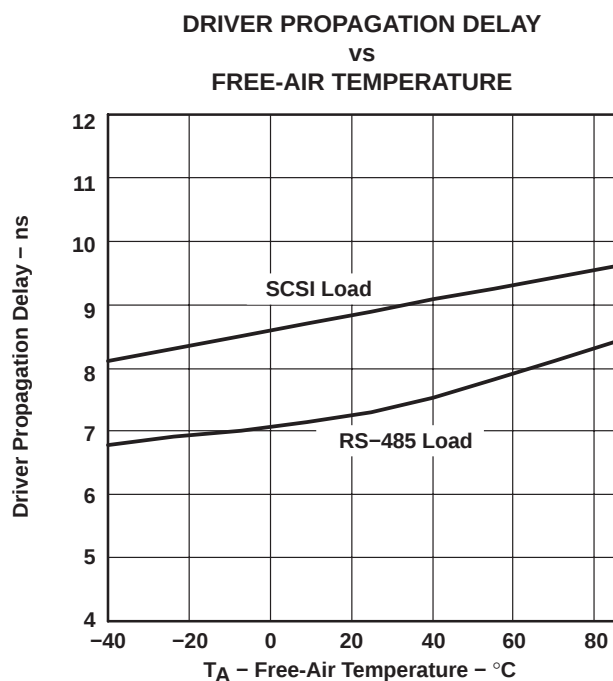


Figure 15

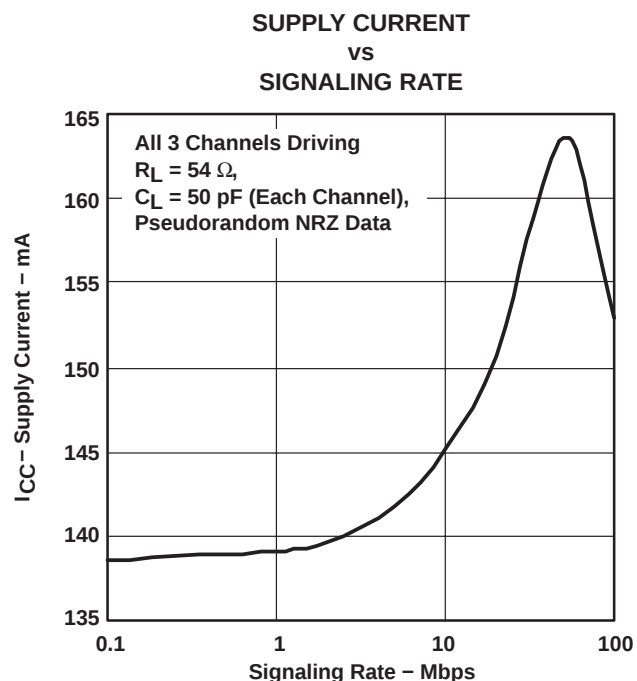


Figure 16

TYPICAL CHARACTERISTICS

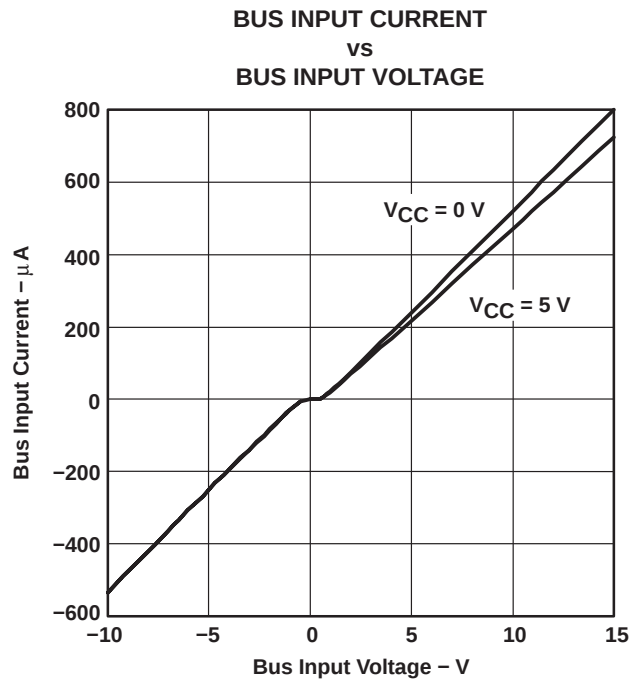


Figure 17

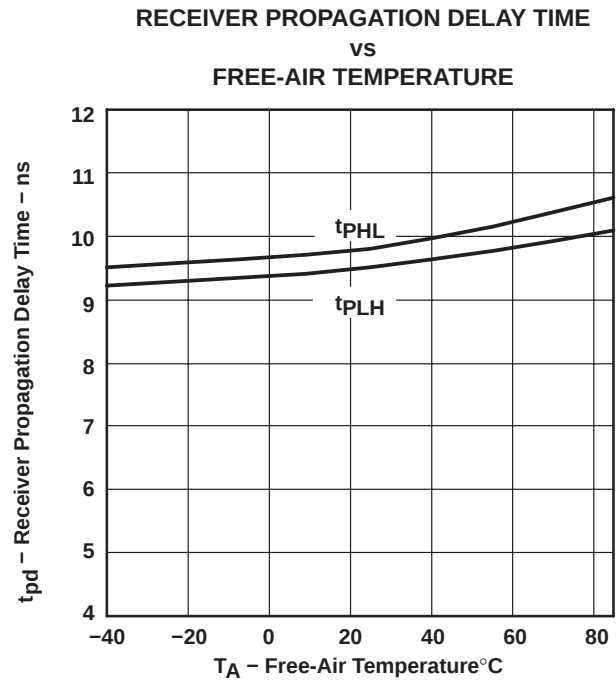


Figure 18

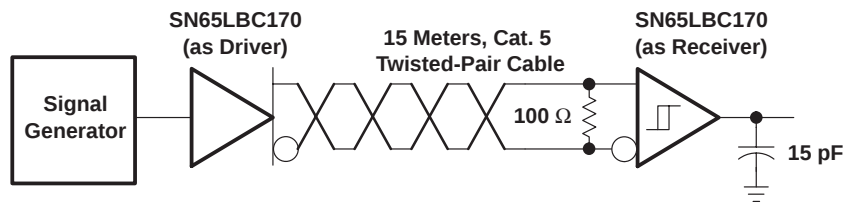


Figure 19. Circuit Diagram for Signaling Characteristics

SN65LBC170, SN75LBC170 TRIPLE DIFFERENTIAL TRANSCEIVERS

SLLS459C – NOVEMBER 2000 – REVISED MARCH 2005

TYPICAL CHARACTERISTICS

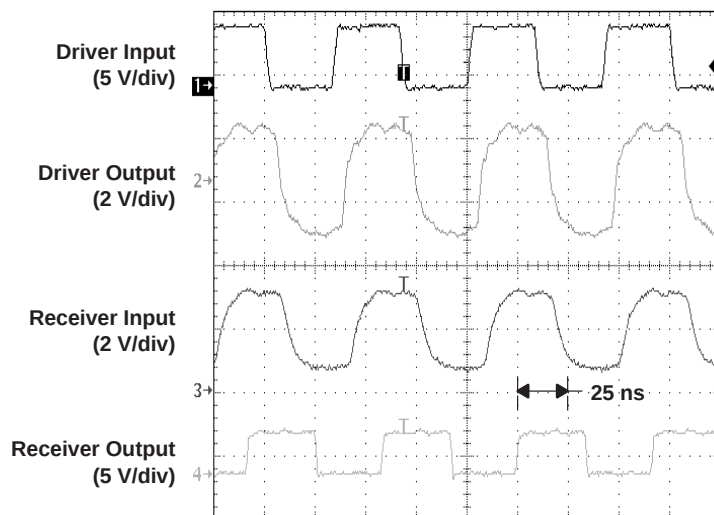


Figure 20. Signal Waveforms at 30 Mbps

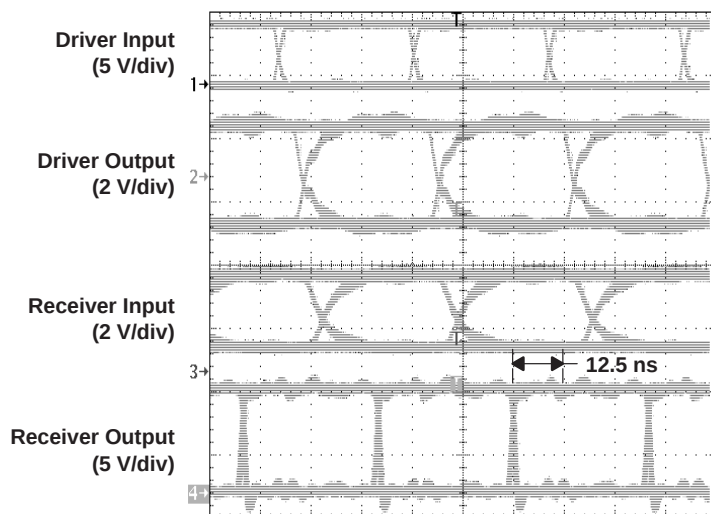


Figure 21. Eye Patterns, Pseudorandom Data at 30 Mbps

TYPICAL CHARACTERISTICS

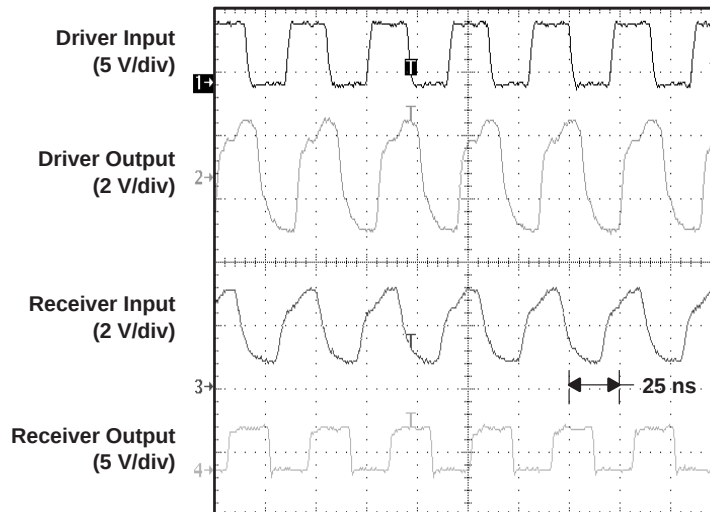


Figure 22. Signal Waveforms at 50 Mbps

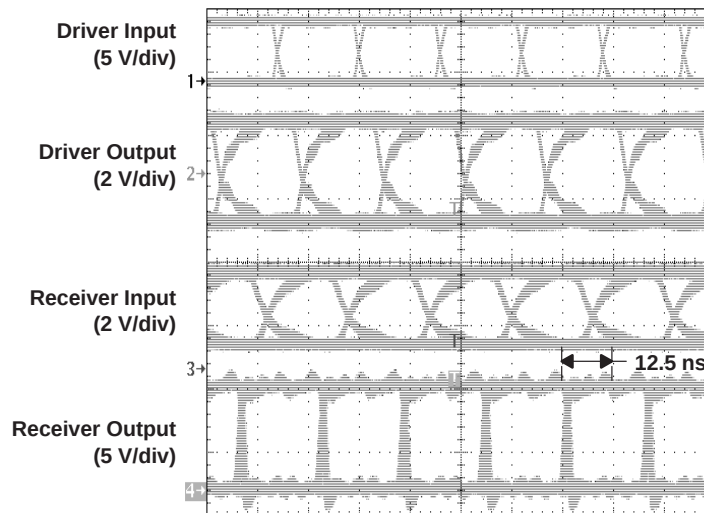


Figure 23. Eye Patterns, Pseudorandom Data at 50 Mbps

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
SN65LBC170DB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DBG4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC170	Samples
SN65LBC170DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC170	Samples
SN75LBC170DB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBG4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC170DBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75LBC170DBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

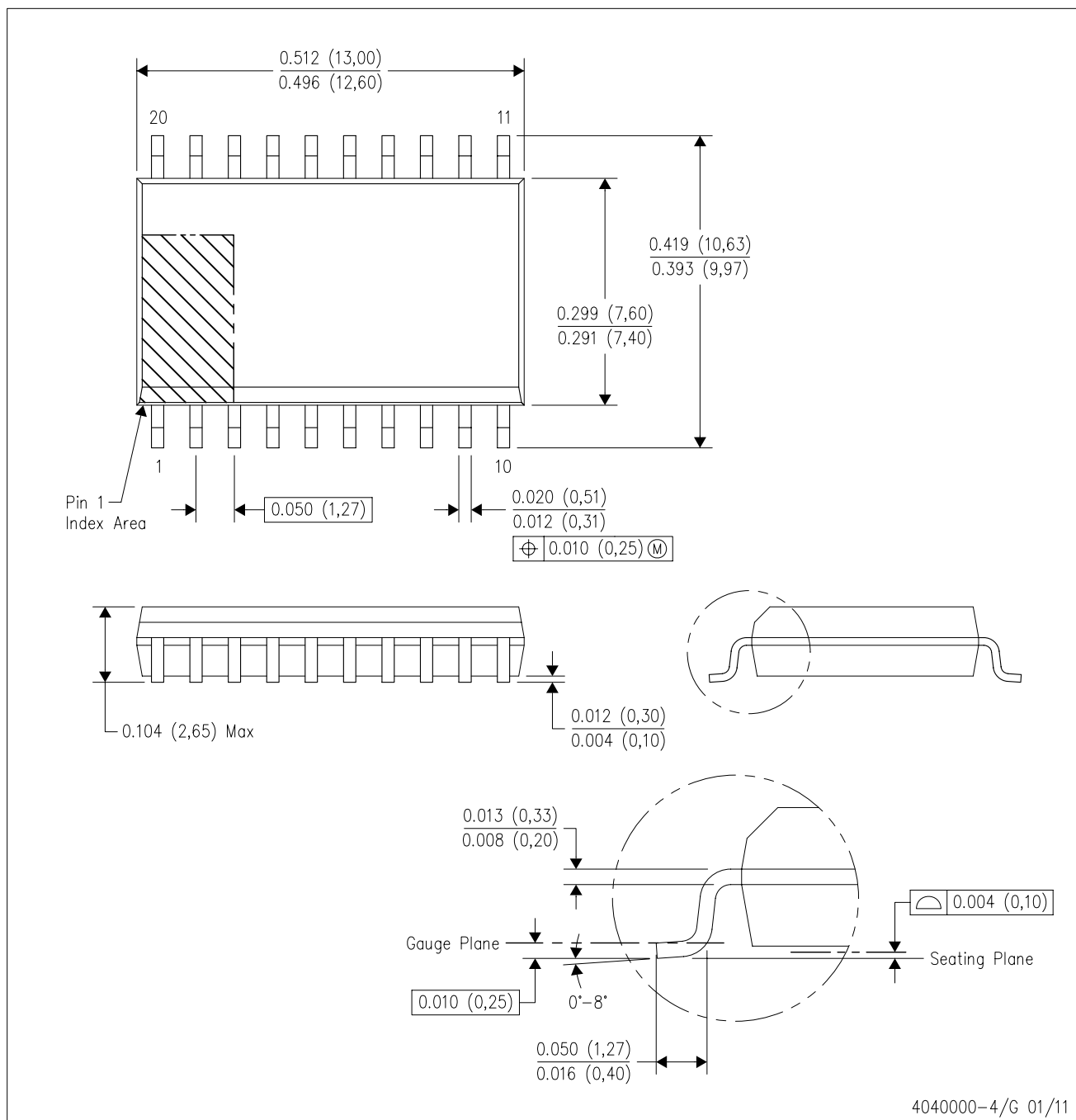


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC170DBR	SSOP	DB	16	2000	367.0	367.0	38.0
SN75LBC170DBR	SSOP	DB	16	2000	367.0	367.0	38.0

DW (R-PDSO-G20)

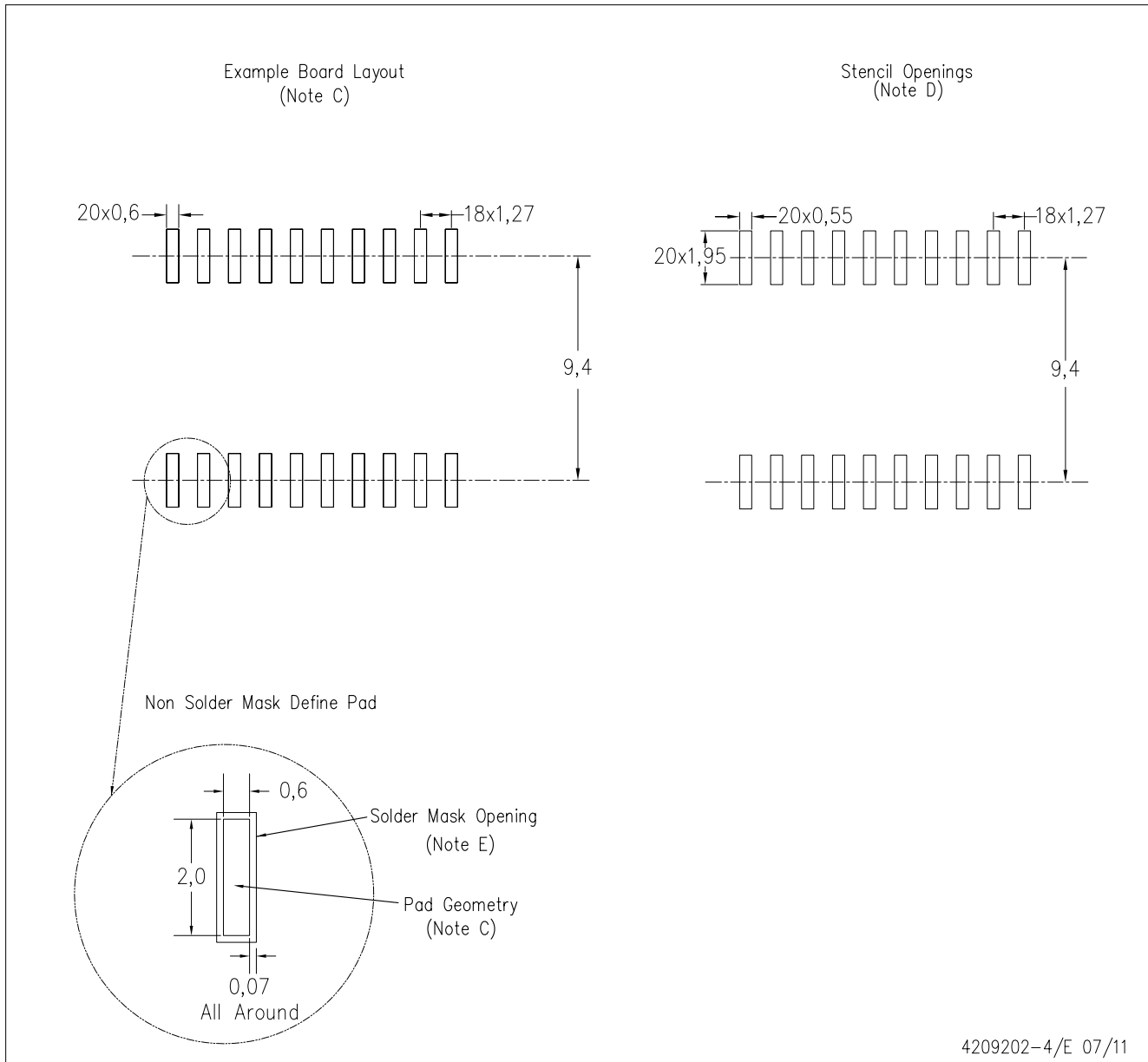
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AC.

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Refer to IPC7351 for alternate board design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-150

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.